NSN 5961-00-403-3979

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-403-3979 **Inclosure Material:** Glass and metal **Overall Length:** 0.390 inches **Terminal Length:** 0.260 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.437 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 300.0 breakover voltage, dc **Current Rating Per Characteristic:** 4.20 amperes forward current, average universal **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 2 tab, solder lug Shelf Life: N/a **Unit Of Measure:** Demilitarization: No

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